

P-Channel 150 V (D-S) MOSFET

PRODUCT SUMMARY

V_{DS} (V)	$R_{DS(on)}$ (Ω)	I_D (A)	Q_g (Typ.)
- 150	0.295 at $V_{GS} = - 10$ V	- 8.9 ^e	23.2 nC
	0.315 at $V_{GS} = - 6$ V	- 8.6 ^e	

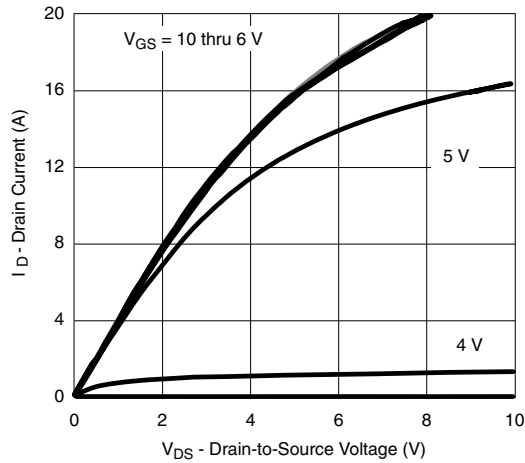
THERMAL RESISTANCE RATINGS

Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^{a, b}	$t \leq 10$ s	R_{thJA}	26	33	°C/W
Maximum Junction-to-Case (Drain)	Steady State	R_{thJC}	1.9	2.4	

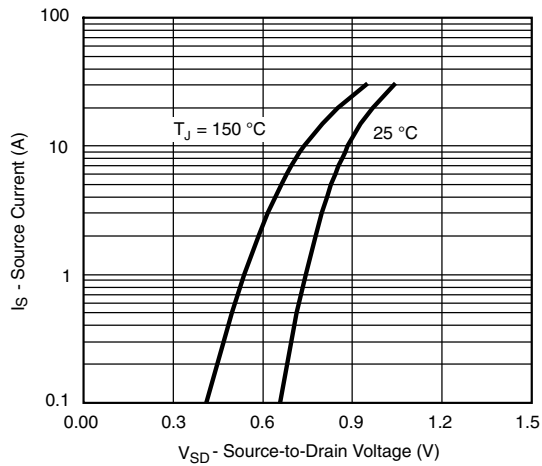
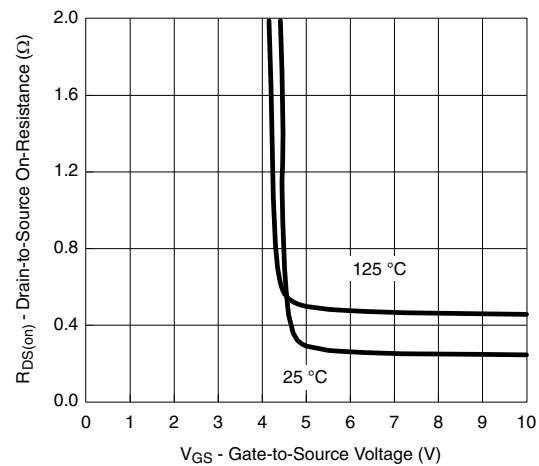
Notes:

a. Surface mounted on 1" x 1" FR4 board.

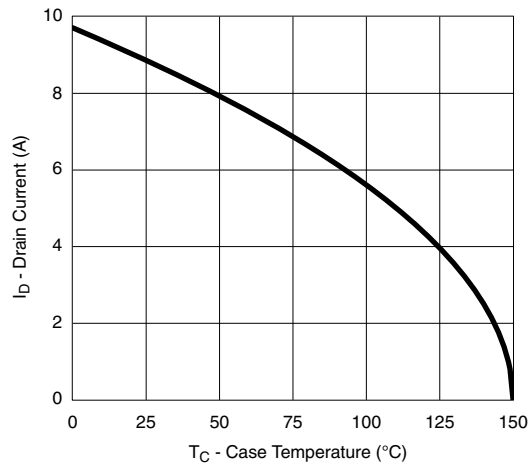
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

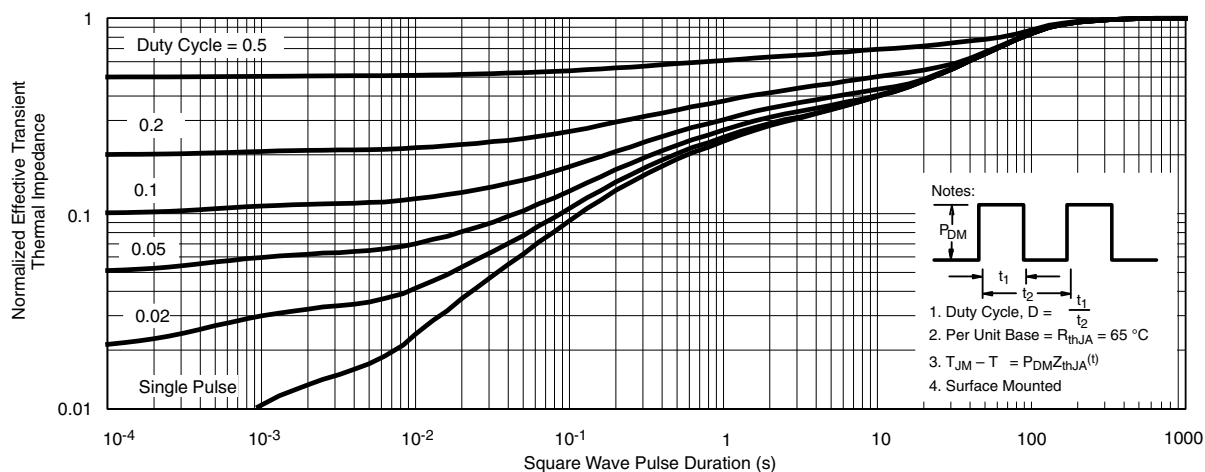


Output Characteristics

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)**Source-Drain Diode Forward Voltage**

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



PowerPAK® 1212, (Single/Dual)



PowerPAK[®] 1212 Mounting and Thermal Considerations

Johnson Zhao

MOSFETs for switching applications are now available with die on resistances around 1 mΩ and with the capability to handle 85 A. While these die capabilities represent a major advance over what was available just a few years ago, it is important for power MOSFET packaging technology to keep pace. It should be obvious that degradation of a high performance die by the package is undesirable. PowerPAK is a new package technology that addresses these issues. The PowerPAK 1212-8 provides ultra-low thermal impedance in a small package that is ideal for space-constrained applications. In this application note, the PowerPAK 1212-8's construction is described. Following this, mounting information is presented. Finally, thermal and electrical performance is discussed.

PowerPAK 1212 DUAL

To take the advantage of the dual PowerPAK 1212-8's thermal performance, the minimum recommended land pattern can be found in Application Note 826, *Recommended Minimum Pad Patterns With Outline Drawing Access for Vishay Siliconix MOSFETs*. Click on the PowerPAK 1212-8 dual in the index of this document.

The gap between the two drain pads is 10 mils. This matches the spacing of the two drain pads on the PowerPAK 1212-8 dual package.

This land pattern can be extended to the left, right, and top of the drawn pattern. This extension will serve to increase the heat dissipation by decreasing the thermal resistance from the foot of the PowerPAK to the PC board and therefore

TABLE 1: EQUIVALENT STEADY STATE PERFORMANCE

Package	SO-8		TSSOP-8		TSOP-8		PPAK 1212		PPAK SO-8	
Configuration	Single	Dual	Single	Dual	Single	Dual	Single	Dual	Single	Dual
Thermal Resistance R_{thJC} (C/W)	20	40	52							



RECOMMENDED MINIMUM PADS FOR PowerPAK® 1212-8 Single





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